

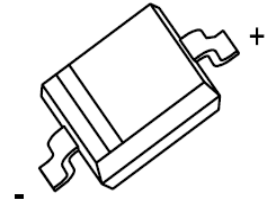


RB501W -40 Schottky Barrier Diode

FEATURES

- Low current rectifier schottky diode
- Low voltage, low inductance
- For power supply

MAKING: 4



SOD-123

Maximum Ratings and Electrical Characteristics, Single Diode @Ta=25°C

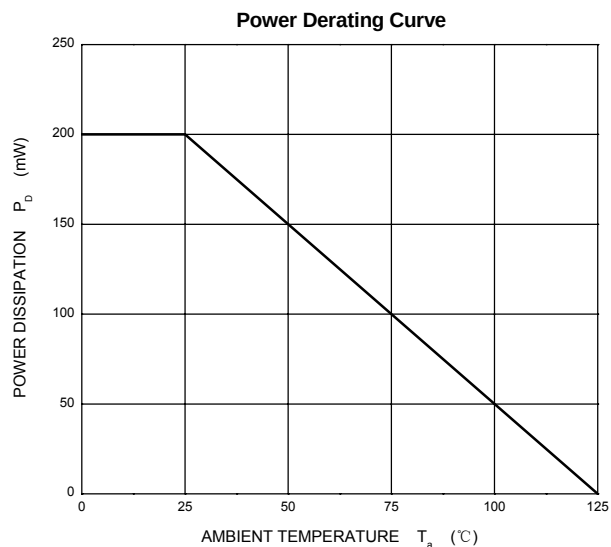
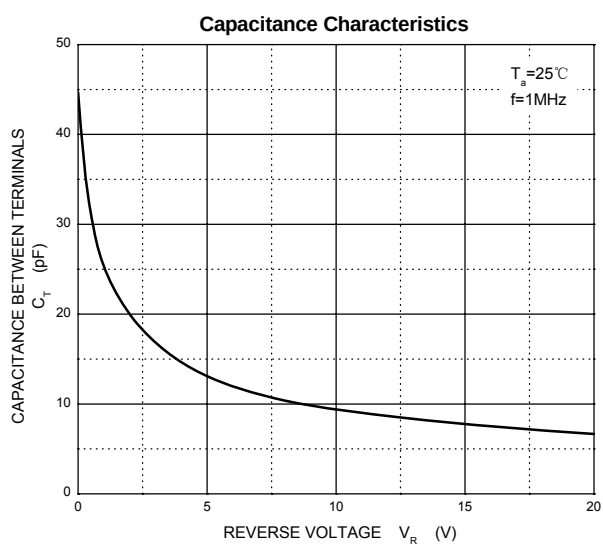
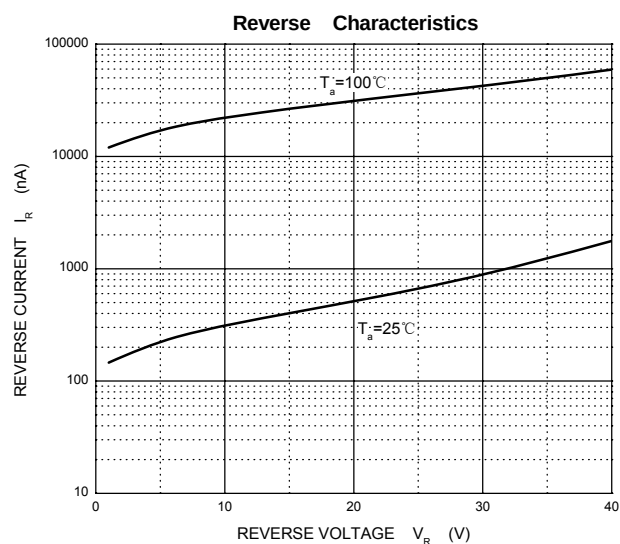
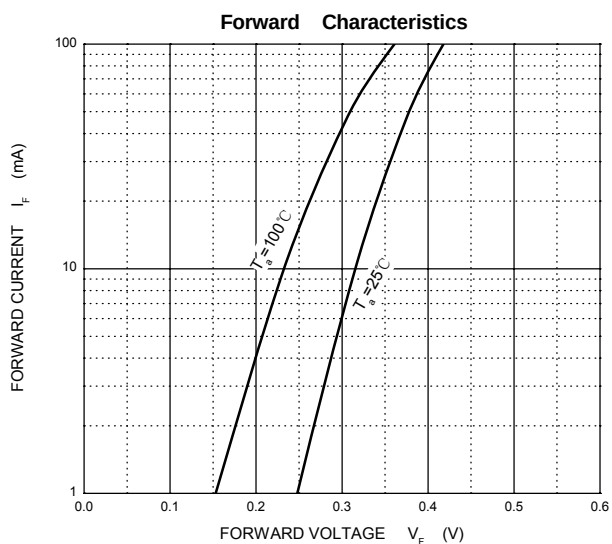
Parameter	Symbol	Limit	Unit
Peak reverse voltage	V_{RM}	45	V
DC reverse voltage	V_R	40	V
Mean rectifying current	I_O	0.1	A
Non-repetitive Peak Forward Surge Current@t=8.3ms	I_{FSM}	1	A
Power dissipation	P_D	200	mW
Thermal Resistance Junction to Ambient	$R_{\theta JA}$	500	°C/W
Junction temperature	T_j	125	°C
Storage temperature	T_{stg}	-55~+150	°C

Electrical Ratings @Ta=25°C

Parameter	Symbol	Min	Typ	Max	Unit	Conditions
Forward voltage	V_F			0.55 0.34	V	$I_F=100mA$ $I_F=10mA$
Reverse current	I_R			30	μA	$V_R=10V$
Capacitance between terminals	C_T		6		pF	$V_R=10V, f=1MHZ$



Typical Characteristics

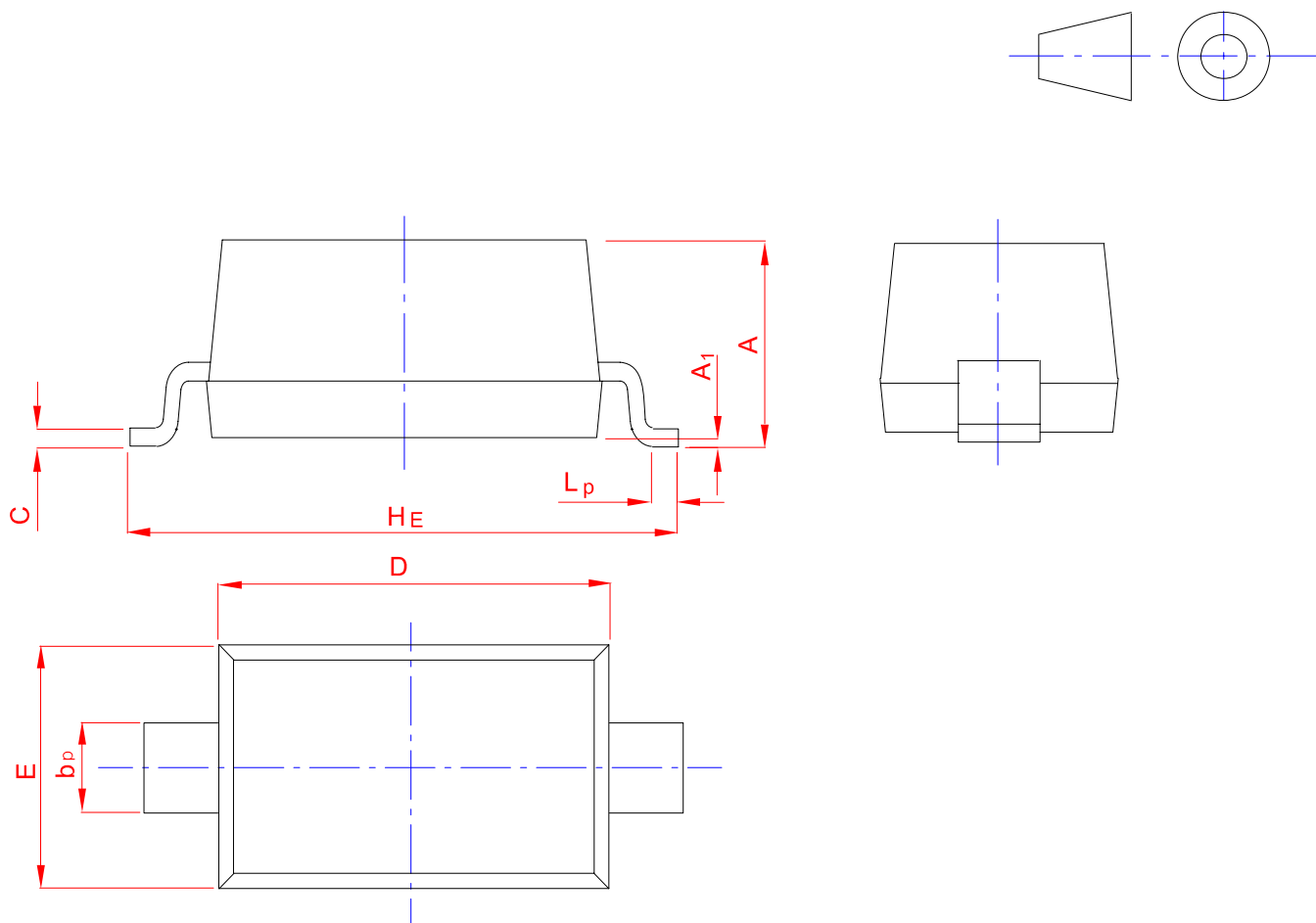




PACKAGE OUTLINE

Plastic surface mounted package; 2 leads

SOD-123



UNIT	A	bp	C	D	E	HE	A1	Lp
mm	1.20 0.90	0.60 0.50	0.135 0.100	2.75 2.55	1.65 1.55	3.85 3.55	0.10 0.01	0.50 0.20